Research Article

Theoretical Investigation of an Air-Slot Mode-Size Matcher between Dielectric and MDM Plasmonic Waveguides

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Hybrid integration of dielectric and plasmonic waveguides is necessary to reduce the propagation losses due to the metallic interactions and support of nanofabrication of plasmonic devices that deal with large data transfer. In this paper, we propose a direct yet efficient, very short air-slot coupler (ASC) of a length of 36 nm to increase the coupling efficiency between a silicon waveguide and a silver-air-silver plasmonic waveguide. Our numerical simulation results show that having the ASC at the interface makes the fabrication process much easier and ensures that light couples from a dielectric waveguide into and out of a plasmonic waveguide. The proposed coupler works over a broad frequency range achieving a coupling efficiency of 86% from a dielectric waveguide into a metal-dielectric-metal (MDM) plasmonic waveguide and 68% from a dielectric waveguide to an MDM plasmonic waveguide and back into another dielectric waveguide. In addition, we show that even if there are no high-precision fabrication techniques, light couples from a conventional dielectric waveguide (CDW) into an MDM plasmonic waveguide as long as there is an overlap between the CDW and ASC, which reduces the fabrication process tremendously. Our proposed coupler has an impact on the miniaturization of ultracompact nanoplasmonic devices.

1. Introduction

Efficient coupling of light into a metal-dielectric-metal (MDM) waveguide from a conventional dielectric waveguide (CDW) is the future of the on-chip applications of the plasmonic devices such as splitters [1, 2], Mach–Zehnder interferometers [3, 4], reflectors [5], wavelength demultiplexers [6], circulators [7], filters [8], and all-optical switching [9]. Other methods of controlling the flow of light in subwavelength regime involve using phase-change materials (PCMs) such as germanium-antimony-telluride (Ge$_2$Sb$_2$Te$_5$) that achieve fast switching speeds by controlling their index of refraction. In [10, 11], the authors experimentally demonstrated the integration of a PCM with hybrid metal-dielectric metasurfaces to control the amplitude, phase, and polarization of the incident optical wavefront. In our research paper, the low-loss CDWs are used to couple light into and out of the plasmonic waveguides that have large propagation losses due to their large metallic interactions. Several different structures have been proposed to achieve mode matching between a CDW and an MDM plasmonic waveguide [12–20]. These solutions are not practical to fabricate or too long for ultracompact integrated circuits. One solution in the literature that has attracted a lot of attention is proposed using a very compact air-gap coupler (AGC) at the interface between a MDM plasmonic waveguide and CDW [21]. The proposed AGC provided a large fabrication tolerance in addition to high transmission coupling efficiency (TCE) into the output dielectric waveguide. Another solution that attracted a lot of attention, because of its simple and compact design, is the air-slot coupler (ASC) that we proposed in [22]. The proposed ASC was fabricated between a 460 nm-wide silicon waveguide and 80 nm-wide gold-air-gold plasmonic waveguide. The TCE was about 40% when the length of the MDM waveguide was 500 nm. The proposed ASC couples light from the CDW into the ASC waveguide before it is coupled into the MDM plasmonic waveguide. The air-slot waveguide that is located inside the CDW at the interface with the MDM plasmonic waveguide is the ASC. Having the ASC at the interface with the CDW ensures that light couples from the CDW into and out of the MDM plasmonic waveguide. In this paper, we
show the design steps and numerical results of a very compact ASC which is smaller than that reported in our previous work in [22], has better TCE into the output CDW, and requires the use of less-precision fabrication techniques. Our proposed ASC is between a 300 nm-wide silicon waveguide and a 40 nm-wide silver-air-silver plasmonic waveguide. In addition, we show the sensitivity of our designs to different fabrication challenges.

The proposed ASCs were designed and analyzed using a two-dimensional (2D) finite-difference time-domain method. We used a uniform mesh size of 1 nm to accurately capture the changes of the field at the interface of the CDW, ASC, and MDM plasmonic waveguides. The dielectric material of the CDW is silicon, and that of the metal is silver. The TCE in our analysis is calculated by normalizing the output power measured at the output CDW with respect to the input power of the launched light, while the CE in our analysis is calculated by normalizing the power measured inside the MDM plasmonic waveguide with respect to the input power of the launched light. The propagation losses of the MDM plasmonic waveguides are included in our numerical results, while those of the CDWs are not included to show the effect of using the ASC on the CE.

The remainder of this paper is organized as follows: in Section 2, we explain the designs and results of the ASC. We also show how increasing the width of the CDW can increase the CE into the MDM plasmonic waveguide. In Section 3, we compare the spectrum results of the proposed ASCs. In Section 4, we show how our proposed designs increase the fabrication tolerance which is needed when aligning the dielectric waveguide to the plasmonic waveguide. Finally, in Section 5, we provide conclusions.

2. Air-Slot Coupler Design, Analysis, and Fabrication

Figure 1(a) shows the schematics of our proposed ASC #1. The ASC is located inside the CDW at the interface between a 300 nm-wide CDW and a 40 nm-wide MDM plasmonic waveguide. The dependence of the CE on the width of the CDW, $W_{\text{Si}}$, over a length of $L_{\text{Si}}$ before it is connected to the MDM plasmonic waveguide (the new design is called ASC #2; see Figure 1(c)). As shown in Figure 1(d), the CE of ASC #2 increased from 80% to about 86% when $W_{\text{Si}}$ increased from 300 nm to 360 nm over a length of $L_{\text{Si}} = 360$ nm. Even though the back reflection of ASC #2 increased slightly to 0.025% compared to 0% in ASC #1, expanding the width of the CDW acted as a fine-tuning mode size to match the mode size inside the CDW to that in the slot waveguide.

To study the TCE from a 300 nm-wide CDW into a 40 nm-wide MDM plasmonic waveguide and back into a 300 nm-wide CDW, the MDM plasmonic waveguide with the ASC is embedded between two CDWs. ASC #1 is connected back to back with another ASC #1 (the new design is called ASC #3; see Figure 2(a)), and ASC #2 is connected back to back with another ASC #2 (the new design is called ASC #4; see Figure 2(b)). In both designs, ASCs #3 and #4, the ASC of a length of 36 nm is placed at each end of the MDM plasmonic waveguide. In order to find the optimum design dimensions, we compared the dependence of the TCE of ASC #3 with that of ASC #4 as a function of the length of the MDM waveguide, $L_{\text{MDM}}$; see Figure 2(c). As shown in Figure 2(c), the oscillations in the measured TCE occurred due to the slot waveguide behaving as a Fabry–Perot (FP) cavity-like structure. As $L_{\text{MDM}}$ increases, the TCE decreases due to the metallic propagation losses in the MDM plasmonic waveguide. Less oscillations with higher TCE are achieved by using ASC #4. Both designs, ASCs #3 and #4, achieved higher TCE than that reported in [22]. The field distributions of the coupled light at 1550 nm for ASCs #3 and #4 are shown in Figures 2(d) and 2(e) when $L_{\text{MDM}} = 740$ nm.

ASC #4 could be fabricated on a 250 nm silicon-on-insulator wafer. First, the alignment marks are defined, and then the dielectric waveguides are placed at specific locations from the alignment marks, followed by etching the silicon layer at the areas where the silver layer is defined. Then, a platinum layer is deposited on top of the silver layer before using the FIB to define the air-slot waveguides.

3. Spectrum Analysis

The spectrum of the proposed ASCs #3 and #4 is shown in Figure 3. The wavelength varied from 400 nm to 2400 nm in steps of 25 nm. At each step, the TCE into the output CDW was measured. The length of the MDM plasmonic waveguide, $L_{\text{MDM}}$, was chosen as 740 nm which represents the second peak in Figure 2(c). The spectrum of the butt coupling with and without applying the $W_{\text{Si}}$ width expansion (i.e., $L_{\text{ASC}} = 0$ nm) was also added to Figure 3 to show that using the ASC increases the TCE around the communication wavelength of 1550 nm for the two proposed couplers. In comparing the spectrum of ASCs #3 and #4, we found that tapering the CDW not only resulted in a higher TCE into the output CDW but also shifted the spectrum response by about 100 nm to the right.

Our proposed ASC #4 with the $W_{\text{Si}}$ width expansion can be used in different sensing applications to show that the refractive index of the slot waveguide, $n_{\text{slot}}$ (i.e., the dielectric in the MDM plasmonic waveguide in addition to that in the
ASC) was changed from 1 (air) to 3.5 (silicon) in steps of 0.5 while keeping $L_{MDM}$ at 740 nm (as shown in Figure 4). As $n_{Slot}$ increases, the TCE decreases, and the shape of the spectrum changes as a result of the poor coupling from the CDW into the slot waveguide in addition to the oscillations in the slot waveguide that behaved like an FP cavity-like structure. The TCE value is zero from about 950 nm to about 1150 nm for all types of $n_{Slot}$.

4. Analysis of the Sensitivity of the Design to Different Fabrication Challenges

We investigated the effect of changing various parameters of the design on the spectrum response of our proposed ASC #4. The investigated parameters are shown in Figure 5(a): the length of the air-slot coupler inside the silicon waveguide, $L_{ASC}$; the length of the MDM plasmonic waveguide, $L_{MDM}$; the width of the silicon waveguide, $W_{Si}$; the width of the slot waveguide, $W_{Slot}$; and the misalignment between the position of the MDM plasmonic waveguide with respect to the center of the silicon waveguide, $S$. We changed one parameter at a time and studied its effect on the spectrum response. The used optimum values for $L_{ASC}$, $L_{MDM}$, $W_{Si}$, $W_{Slot}$, and $S$ were 36 nm, 740 nm, 360 nm, 40 nm, and 0 nm, respectively. We found that changing $L_{ASC}$ from 0 nm (i.e., butt coupling) to 400 nm resulted in a reduction in the width of the spectrum response mainly due to the FP cavity-like structure; see Figure 5(b). The highest TCE with the largest spectrum width occurred when $L_{ASC} = 36$ nm. Three lengths of $L_{MDM}$ were investigated, 220 nm, 560 nm, and 740 nm, which represent the first peak, the first valley, and the second peak in Figure 2(a), respectively. We found that almost no change occurred in the spectrum shape when $L_{MDM}$ is changed except for the reduction in the TCE due to the metallic interactions; see Figure 5(c). We also found that the cutoff wavelength can be controlled by changing $W_{Si}$ (see Figure 5(d)) and $W_{Slot}$ (see Figure 5(e)). Changing $W_{Si}$ from 360 nm to 440 nm resulted in shifting the cutoff wavelength from about 1100 nm to 1300 nm, respectively, whereas changing $W_{Slot}$ from 40 nm to 120 nm resulted in shifting the cutoff wavelength from

![Figure 1](image-url)
Figure 2: The schematics of the proposed ASCs #3 and #4 that show how light couples into and out of the MDM plasmonic waveguide: (a) ASC #3 without the dielectric width expansion that resulted from connecting two #1 ASCs back to back, (b) ASC #4 with the dielectric width expansion that resulted from connecting two #2 ASCs back to back, (c) transmission coupling efficiency as a function of the length of the MDM plasmonic waveguide, $L_{MDM}$, for both ASCs #3 and #4, and (d,e) field distributions of the coupled light at 1550 nm for ASCs #3 and #4 when $L_{MDM} = 740$ nm.
about 1100 nm to 1000 nm, respectively. Finally, we found that changing $S$ from 0 nm to 80 nm resulted in a reduction in the width of the spectrum response in addition to a reduction in the TCE due to the reduction in the overlapped area between the mode supported by the slot waveguide and that supported by the silicon waveguide; see Figure 5(f). This analysis shows the impact of different key design parameters on the spectrum response of the device which indicates that using the ASC reduces the need for high-precision fabrication process tremendously.
Figure 5: Continued.
5. Conclusions

We numerically showed that a very short ASC of a length of 36 nm and a width of 40 nm can be used to couple light from a 40 nm-wide silicon waveguide into a 40 nm-wide MDM plasmonic waveguide. When changing the key design parameters (i.e., the width of the silicon waveguide; the length of the MDM plasmonic waveguide; and the length, width, and position of the ASC), our results indicated that using our proposed ASC reduced the need for high-precision fabrication processes tremendously. Moreover, the spectrum of the proposed ASC operated at a broad frequency range around the communication wavelength of 1550 nm.

Data Availability

I did many simulations using the FDTD method to get all the results that I showed in the submitted research work. I described all the required information that one needs to redo the same design so that he/she gets the same results.

Conflicts of Interest

The author declares that there are no conflicts of interest.

References


